Analog Power AM7100N

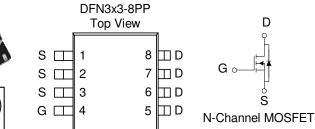
N-Channel 100-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY					
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$			
100	$62 @ V_{GS} = 10V$	6.2			
100	$72 @ V_{GS} = 4.5V$	5.7			







ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			100	V	
Gate-Source Voltage	V_{GS}	±20	V		
C .: B . C .a	$T_A=25^{\circ}C$] T	±6.2		
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	±5.1	A	
Pulsed Drain Current ^b	I_{DM}	±75			
Continuous Source Current (Diode Conduction) ^a		I_S	16	A	
D	$T_A=25^{\circ}C$	D	3.5	W	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	r _D	2	VV	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
Maximum Junction-to-Case ^a	t <= 5 sec	$R_{ heta JC}$	25	°C/W		
Maximum Junction-to-Ambient ^a	t <= 5 sec	$R_{ heta JA}$	50	°C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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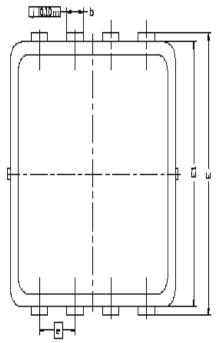
Parameter	Cymbal	Test Conditions	Limits			 Unit	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Umt	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$, $I_D = 250 \mathrm{uA}$	1			V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zelo Gate Voltage Diam Current	1088	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α	
D : G . O D : A	45.0()	$V_{GS} = 10 \text{ V}, I_{D} = 1 \text{ A}$			62		
Drain-Source On-Resistance ^A	fDS(on)	$V_{GS} = 4.5 \text{ V}, I_{D} = 1 \text{ A}$			72	mΩ	
Forward Tranconductance ^A	gs	$V_{DS} = 15 \text{ V}, I_{D} = 1 \text{ A}$		40		S	
Diode Forward Voltage	Vsd	Is = 1 A, VGS = 0 V		0.7		V	
Dynamic ^b							
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		13			
Gate-Source Charge	Q_{gs}	VDS = 15 V, VGS = 4.5 V, $ID = 9 A$		3		nC	
Gate-Drain Charge	Qgd	ID = 9 A		6			
Input Capacitance	Ciss	V 15 V V 0 V		1100			
Output Capacitance	Coss	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz		120		pF	
Reverse Transfer Capacitance	Crss			70			
Turn-On Delay Time	t _{d(on)}			11			
Rise Time	tr	$V_{DD} = 25 \text{ V}, R_L = 25 \Omega, I_D = 1 \text{ A},$ $V_{GEN} = 10 \text{ V}$		12			
Turn-Off Delay Time	td(off)			50		nS	
Fall-Time	t_{f}			30		Ī	

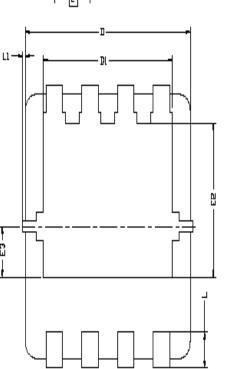
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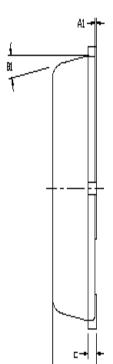
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information







TITLE	HOLLIMETERS			CNCHES		
IIIM,	MIN	MON	MAX	MIM	NDN	MAX
h	0,700	0,80	0,900	0.0276	0,0315	M354
AL	ָרָרָן, קרָרָן		1,05	וַסְסָוּ,		0.005
Ь	0.24	0.30	0,35	0.009	0.012	0.014
	0.10	0.152	0.25	0,004	0.006	0,010
D	3.00 BSC			0.11B RCC		
	ň	.35 BS	л u	028 Ee0.0		
	7	320 BSC				
EL	3.00 BSC			O'IIB B2C		
E5	1.75 BSC			0.069 BSC		
[3	0.575 BSC			0.023 BSC		
2	0.65 BSC			0.026 BSC		
L	0.30	0.40	1,50	0,0118	0.0157	0.0197
	0		0.100	0		0.004
B1	D,	10*	12*	ינן	10*	12*